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CLAIMS

What is claimed is:

- 1. A method of producing an integrated circuit (IC) device layout representation corresponding to an IC device design, said method comprising:
 - (a) generating an initial layout representation in accordance with a plurality of design rules;
 - (b) simulating how structures within at least a portion of the initial layout representation will pattern on a wafer;
- (c) based on the simulating step, identifying portions of the layout representation which include structures demonstrating poor manufacturability;
- (d) based on the simulating step, identifying portions of the layout representation in which extra manufacturability margin is present; and
- (e) modifying at least one of (i) portions of the layout representation
 which include structures demonstrating poor manufacturability and (ii) portions of the layout representation in which extra manufacturability margin is present.
 - 2. The method of claim 1, said method further comprising:
 - (f) simulating how structures within at least a portion of the modified layout representation will pattern on a wafer; and
 - (g) repeating steps (c) (f) until no portions of the layout representation demonstrate poor manufacturability.
- The method of claim 1, said method further comprising:
 performing at least one optical proximity correction (OPC) on the initial layout representation before step (b).
- The method of claim 1, wherein step (c) includes: performing optical rule checking (ORC) on the simulated layout
 representation.

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5. The method of claim 4, wherein performing ORC includes checking at least one of aerial image metrics, resist image metrics and post exposure bake metrics.

- 5 6. The method of claim 5, wherein ORC is performed on one or more portions of the simulated layout representation over a process window of focus and intensity.
- 7. The method of claim 5, wherein the aerial image metrics include at least one of image edge slope, image edge log slope, contrast, minimum intensity, maximum intensity, edge placement error and intensity at a given distance.
 - 8. The method of claim 1, wherein step (c) includes:
 defining a manufacturability figure of merit (FOM); and
 evaluating the manufacturability of at least a portion of the simulated
 layout representation based on the manufacturability FOM.
- 9. The method of claim 8, wherein defining a manufacturability FOM 20 includes:

identifying one or more metrics which are indicative of a manufacturable layout representation; and

selecting acceptable ranges for the one or more metrics.

- 25 10. The method of claim 9, wherein the evaluating step includes: performing optical rule checking (ORC) on the simulated layout representation using the selected acceptable ranges for the one or more metrics.
- 11. The method of claim 10, wherein the one or more metrics include at least one of image edge slope, image edge log slope, contrast, minimum intensity, maximum intensity, edge placement error and intensity at a given distance.

12. The method of claim of claim 9, wherein defining a manufacturability FOM includes:

selecting an exemplary layout;

generating a simulation image corresponding to how the selected exemplary layout pattern will pattern on a wafer;

evaluating a scanning electron microscope (SEM) image of the selected exemplary layout portion printed on a wafer;

identifying areas on the SEM image that are problematic with respect to manufacturability; and

for each problematic area on the SEM image, locating the corresponding portion of the simulation image and determining acceptable ranges for the one or more metrics based on the simulation image.

- 13. The method of claim 1, wherein step (c) includes: identifying metrics which are indicative of a manufacturable layout representation.
- 14. The method of claim 1, wherein for portions of the layout
 20 representation including structures demonstrating poor manufacturability, step (e) includes:

at least one of (i) providing more space between adjacent structures, (ii) decreasing linewidth of one or more structures, and (iii) making edges of one or more structures wider.

15. The method of claim 1, wherein for portions of the layout representation in which extra manufacturability margin is present, step (e) includes:

compacting at least a portion of the layout representation.

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16. The method of claim 1, wherein for portions of the layout representation in which extra manufacturability margin is present, step (e) includes:

at least one of (i) moving outer corners of structures closer to adjacent structures, (ii) moving contacts closer to inner corners of metal lines, (iii) moving contacts closer to polysilicon end caps, (iv) reshaping active or metal layers to maintain width and space, and (v) adding side extensions to polysilicon end caps

- 17. The method of claim 1, wherein step (b) includes simulating how structures will pattern on a wafer as a result of at least one of resolution enhancement technologies (RET), optical proximity correction (OPC), proximity to other structures, density of structures and corner rounding.
- 18. The method of claim 1, wherein step (e) includes violating at leastone of the plurality of design rules.
 - 19. The method of claim 1, wherein step (e) is performed despite there existing no violation of any of the plurality of design rules.
- 20. The method of claim 1, wherein step (c) includes providing a graphical representation indicating structures demonstrating poor manufacturability.
- 21. The method of claim 20, wherein step (d) includes providing a
 25 graphical representation identifying portions of the layout representation in which extra manufacturability margin is present.
 - 22. A method of optimizing a design rule compliant layout, said method comprising:
- defining a manufacturability figure of merit (FOM); simulating how the layout will pattern on a wafer;

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evaluating manufacturability of portions of the layout based on the manufacturability FOM; and

based on the evaluating step, modifying the design rule compliant layout.

5 23. The method of claim 22, wherein defining a manufacturability FOM includes:

identifying one or more metrics which are indicative of a manufacturable layout; and

selecting acceptable ranges for the one or more metrics.

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- 24. The method of claim 23, wherein the evaluating step includes: performing optical rule checking (ORC) on the simulated layout using the selected acceptable ranges for the one or more metrics.
- 15 25. The method of claim 24, wherein ORC is performed on one or more portions of the simulated layout over a process window of focus and intensity.
 - 26. The method of claim 24, wherein the one or more metrics include at least one of image edge slope, image edge log slope, contrast, minimum intensity, maximum intensity, edge placement error and intensity at a given distance.
 - 27. The method of claim 22, wherein modifying the design rule compliant layout includes modifying the layout in violation of at least one design rule with which the layout is compliant.